

Features:

- For AF driver and output stages
- High collector current
- Low collector-emitter saturation voltage
- Complementary types: BCX54/BCX55/BCX56

Applications:

- Medium power general purposes
- Driver stages of audio amplifiers

Pin Configuration:

1. Base
2. Emitter
3. Collector

Maximum Ratings

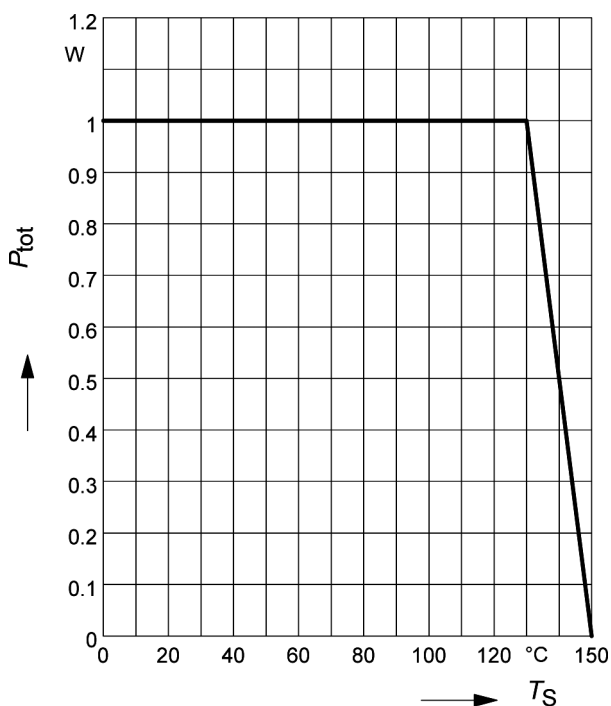
Parameter	Symbol	Value	Unit
Collector - Base Voltage - BCX51 - BCX52 - BCX53	V_{CBO}	-45 -60 -100	V
Collector - Emitter Voltage - BCX51 - BCX52 - BCX53	V_{CEO}	-45 -60 -80	
Emitter - Base Voltage	V_{ebo}	-5	
Collector Current - Continuous	I_C	-1	A
Collector Current - Peak	I_{CM}	-1.5	
Total device Dissipation	P_D	500	mW
Junction and Storage Temperature	T_j, T_{stg}	-65 to +150	°C

PNP Medium Power Transistor **multicomp**PRO

Electrical Characteristics ($T_a = 25^\circ\text{C}$ unless otherwise noted)

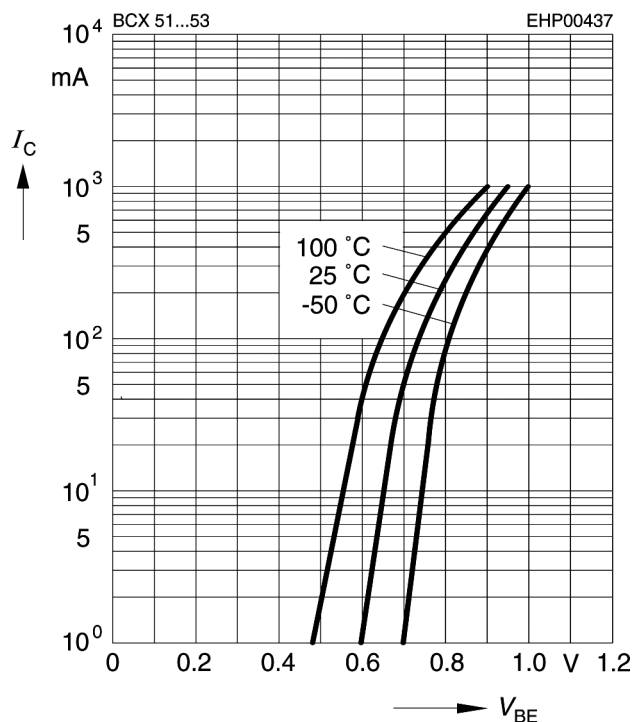
Parameter	Symbol	Test Conditions	Min.	Typ.	Max.	Unit
Collector - Base Breakdown Voltage	$V_{(BR)CBO}$	$I_C = -100\mu\text{A}$, $I_E = 0$ BCX51 BCX52 BCX53	-45 -60 -100			V
Collector - Emitter Breakdown Voltage	$V_{(BR)CEO}$	$I_C = -10\text{mA}$, $I_B = 0$ BCX51 BCX52 BCX53	-45 -60 -80			
Emitter - Base Breakdown Voltage	$V_{(BR)EBO}$	$I_E = -10\mu\text{A}$, $I_C = 0$	-5			
Collector Cut-Off Current	I_{CBO}	$V_{CB} = -30\text{V}$, $I_E = 0$			-0.1	A
DC Current Gain	h_{FE}	$V_{CE} = -2\text{V}$, $I_C = -5\text{mA}$ $V_{CE} = -2\text{V}$, $I_C = -150\text{mA}$ $V_{CE} = -2\text{V}$, $I_C = -150\text{mA}$ -10 -16 $V_{CE} = -2\text{V}$, $I_C = -500\text{mA}$	25 40 63 100 25		250 160 250	
Collector - Emitter Saturation Voltage	$V_{CE(sat)}$	$I_C = -500\text{mA}$, $I_B = -50\text{mA}$			-0.5	V
Base Emitter Voltage	V_{BE}	$I_C = -500\text{mA}$, $V_{CE} = -2\text{V}$			-1	
Transition Frequency	f_T	$V_{CE} = -10$, $I_C = -50$, $f = 20\text{MHz}$		125		MHz

Total power dissipation $P_{tot} = f(T_S)$



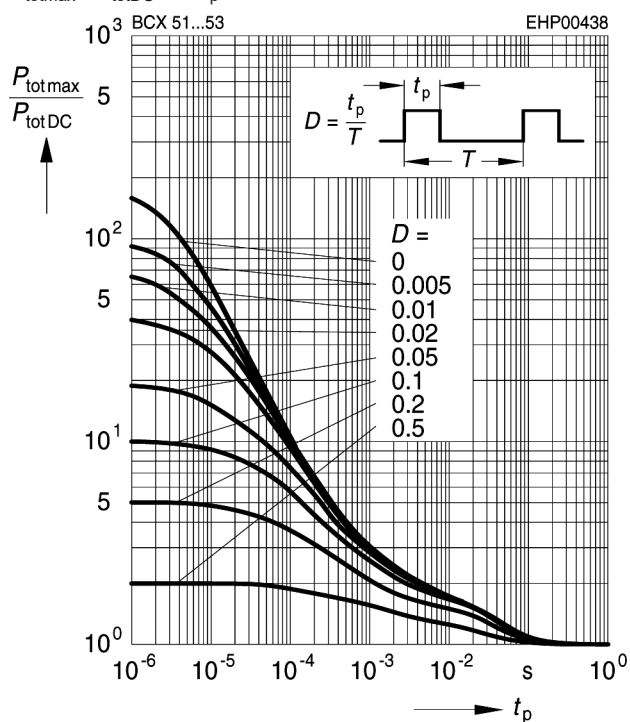
Collector current $I_C = f(V_{BE})$

$V_{CE} = 2\text{V}$



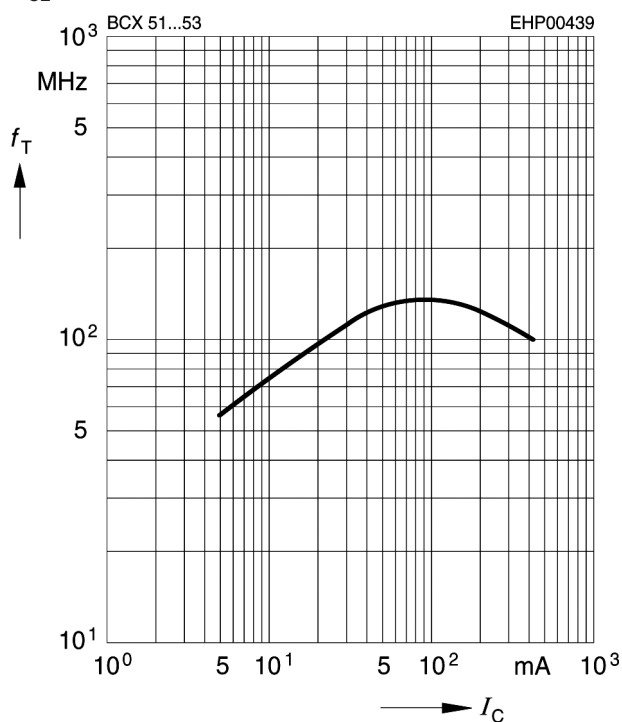
Permissible pulse load

$$P_{\text{totmax}} / P_{\text{totDC}} = f(t_p)$$



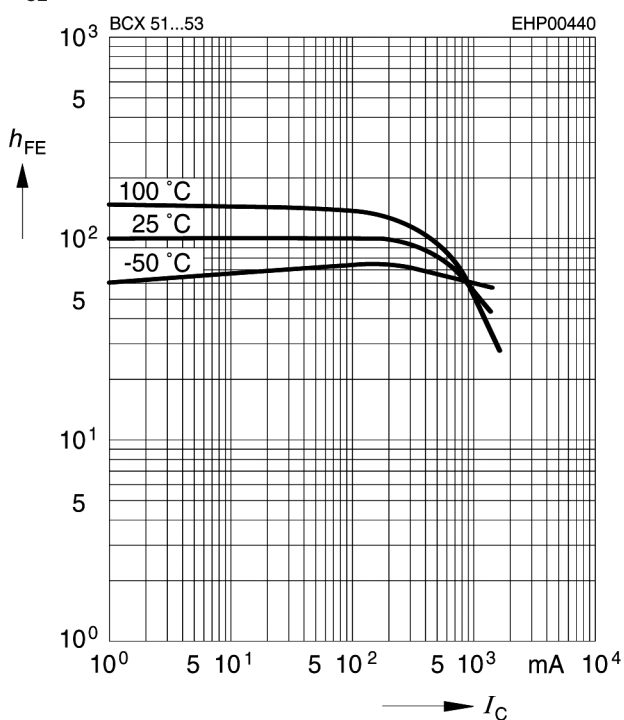
Transition frequency $f_T = f(I_C)$

$$V_{\text{CE}} = 10\text{V}$$



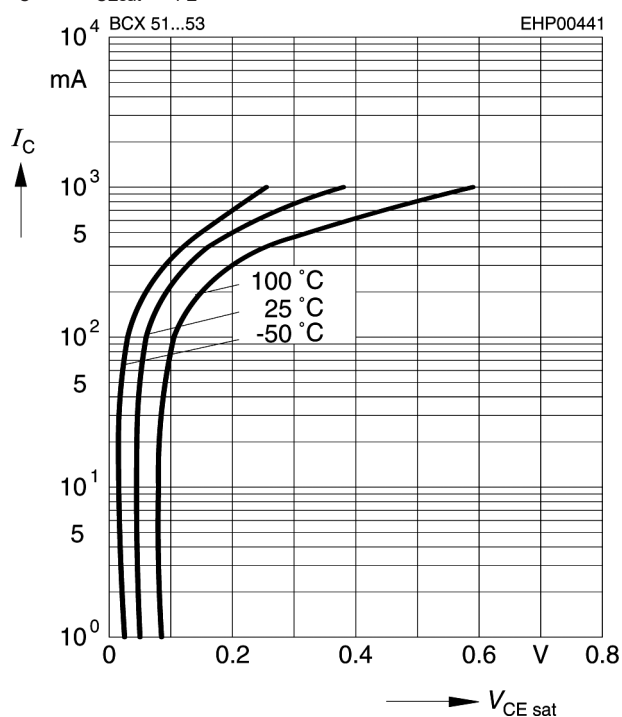
DC current gain $h_{\text{FE}} = f(I_C)$

$$V_{\text{CE}} = 2\text{V}$$



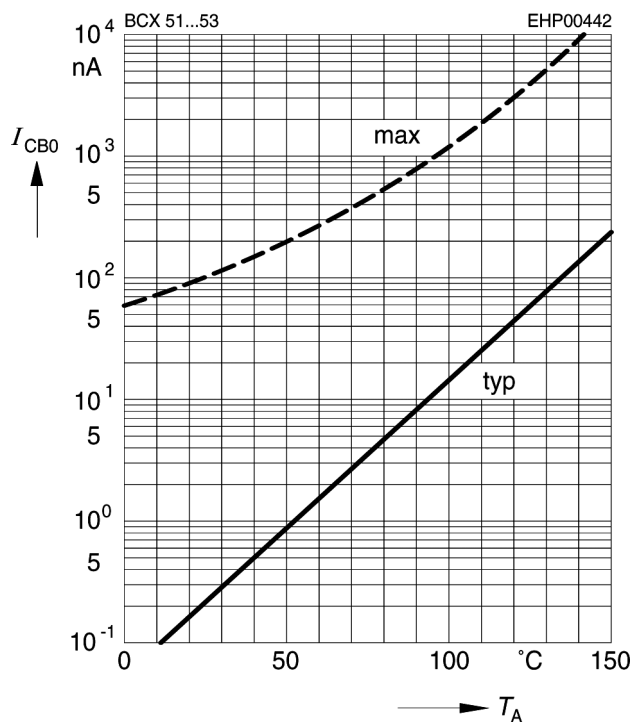
Collector-emitter saturation voltage

$$I_C = f(V_{\text{CEsat}}, h_{\text{FE}} = 10)$$



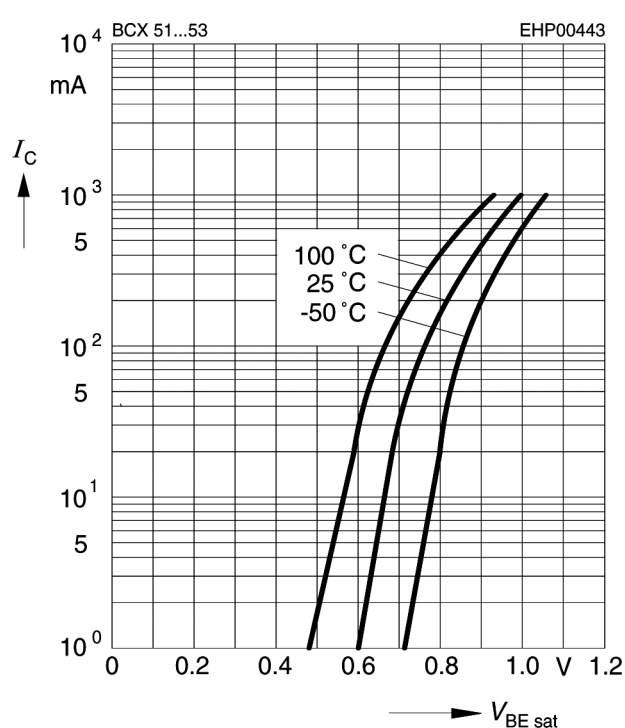
Collector cutoff current $I_{CBO} = f(T_A)$

$V_{CB} = 30V$



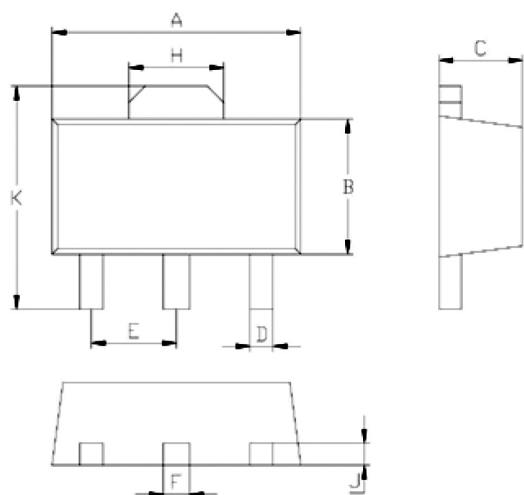
Base-emitter saturation voltage

$I_C = f(V_{BEsat}), h_{FE} = 10$



Package Outline

Plastic surface mounted package



Dimensions	Min.	Max.
A	4.5	4.7
B	2.3	2.7
C	1.5 Typical	
D	0.35	0.55
E	1.4	1.6
F	0.4	0.6
H	1.55	1.75
J	0.4 Typical	
K	4.15	4.25

Dimensions : Millimetres

